

# ST1803DHI

## HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

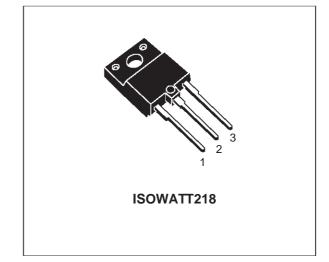
- NEW SERIES, ENHANCHED PERFORMANCE
- FULLY INSULATED PACKAGE FOR EASY MOUNTING
- INTEGRATED FREE WHEELING DIODE
- HIGH VOLTAGE CAPABILITY
- HIGH SWITCHING SPEED
- TIGTHER hfe CONTROL
- IMPROVED RUGGEDNESS

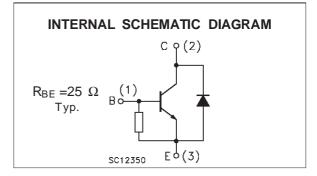
## **APPLICATIONS:**

 HORIZONTAL DEFLECTION FOR COLOR TV

## DESCRIPTION

The ST1803DHI is manufactured using Diffused Collector technology for more stable operation Vs base drive circuit variations resulting in very low worst case dissipation.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage ( $I_E = 0$ )	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage $(I_B = 0)$	600	V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	7	V
lc	Collector Current	10	A
Ісм	Collector Peak Current (t <sub>p</sub> < 5 ms)	15	Α
Ι <sub>Β</sub>	Base Current	4	A
P <sub>tot</sub>	Total Dissipation at $T_c = 25$ °C	50	W
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

## THERMAL DATA

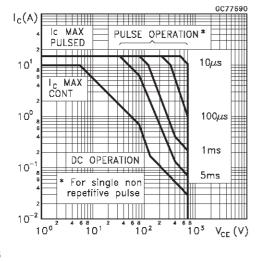
Rthj-case Thermal Resistance Junction-case	Max	2.5	°C/W	
--	-----	-----	------	--

## **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25 \,^{\circ}C$ unless otherwise specified)

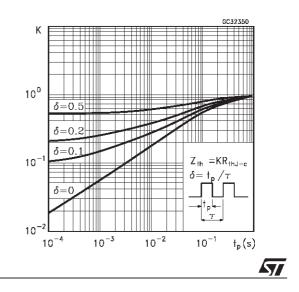
Symbol	Parameter	Test C	onditions	Min.	Тур.	Max.	Unit
ICES	Collector Cut-off Current ( $V_{BE} = 0$ )	V <sub>CE</sub> = 1500 V V <sub>CE</sub> = 1500 V	T <sub>j</sub> = 125 °C			1 2	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_C = 0)$	$V_{EB} = 4 V$		130		400	mA
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	-	в = 0.8 A в = 1.2 A		3	5 1.5	V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4 A I	<sub>B</sub> = 0.8 A			1.2	V
h <sub>FE</sub> *	DC Current Gain	$I_{C} = 1 A$ $I_{C} = 4.5 A$		10 4	15	20 9	
VF	Diode Forward Voltage	I <sub>F</sub> = 5 A			1.5	2	V
BV <sub>EB0</sub>	Emitter-Breakdown Voltage	I <sub>E</sub> = 700 mA		7			V
t <sub>s</sub> t <sub>f</sub>	INDUCTIVE LOAD Storage Time Fall Time		<sub>Bon(END)</sub> = 0.8 A / <sub>BB</sub> = -2.5 V		5 0.3	6 0.6	μs μs

\* Pulsed: Pulse duration = 300 µs, duty cycle 1.5 %

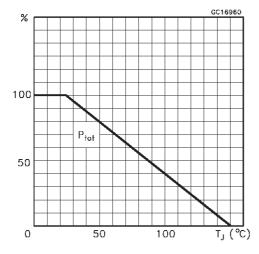
## Safe Operating Area



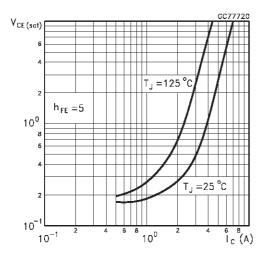
Thermal Impedance



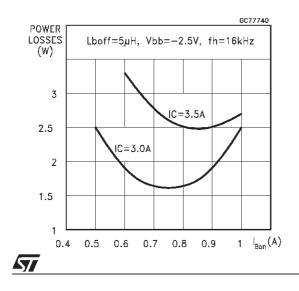
#### **Derating Curve**



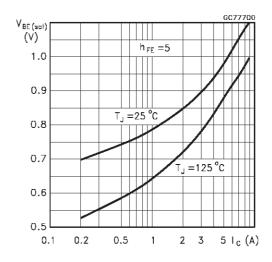
Collector Emitter Saturation Voltage



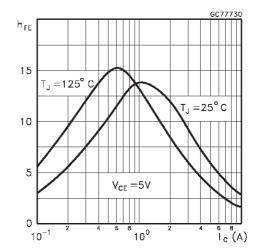




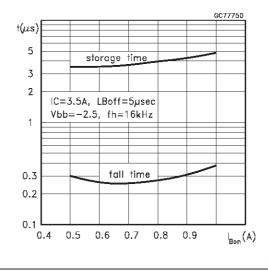
#### **Biase Emitter Saturation Voltage**



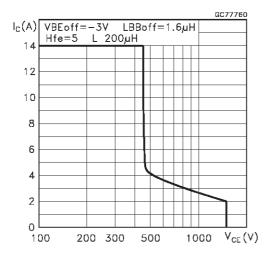
## DC Current Gain



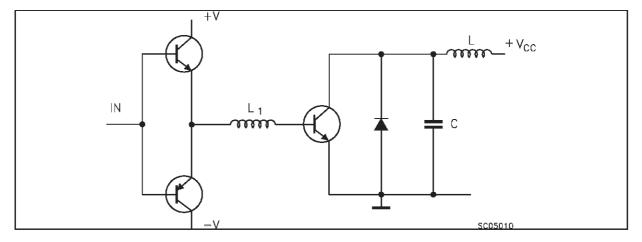




## **Reverse Biased SOA**

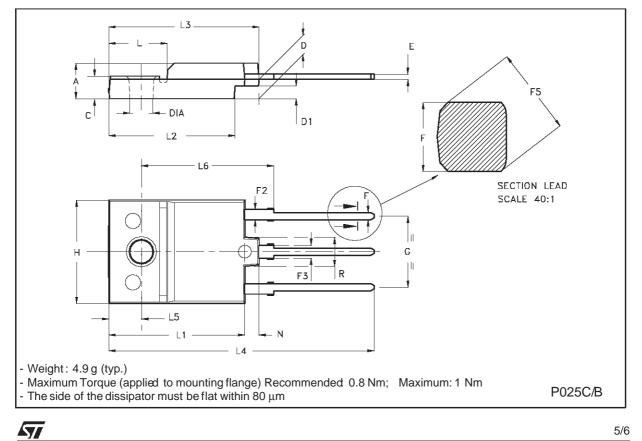


Inductive Load Switching Test Circuits.



DIM.	mm		inch				
DIM.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	5.35		5.65	0.211		0.222	
С	3.30		3.80	0.130		0.150	
D	2.90		3.10	0.114		0.122	
D1	1.88		2.08	0.074		0.082	
Е	0.75		0.95	0.030		0.037	
F	0.75		0.95	0.030		0.037	
F2	1.50		1.70	0.059		0.067	
F3	1.90		2.10	0.075		0.083	
F5			1.10			0.043	
G	10.80		11.20	0.425		0.441	
Н	15.80		16.20	0.622		0.638	
L		9			0.354		
L1	20.80		21.20	0.819		0.835	
L2	19.10		19.90	0.752		0.783	
L3	22.80		23.60	0.898		0.929	
L4	40.50		42.50	1.594		1.673	
L5	4.85		5.25	0.191		0.207	
L6	20.25		20.75	0.797		0.817	
Ν	2.1		2.3	0.083		0.091	
R		4.6			0.181		
DIA	3.5		3.7	0.138		0.146	

## **ISOWATT218 NARROW LEADS MECHANICAL DATA**



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics. The ST logo is a trademark of STMicroelectronics

© 2000 STMicroelectronics – Printed in Italy – All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

http://www.st.com

57

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.